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Lattice dynamics of neodymium: influence of $4f$ electron correlations

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Incorporation of strong electron correlations into the density functional theory (DFT) for the electronic structure calculations of light lanthanides leads to a modification of inter-atomic forces and consequently the lattice dynamics. Using first-principles theory we demonstrate the substantial influence of the $4f$ electron correlations on the phonon dispersion relations of Nd. The calculations are verified by an inelastic X-ray scattering experiment performed on a single-crystalline Nd(0001) film. We show that very good agreement between the calculated and measured data is achieved when electron-electron interactions are treated by the DFT+U approach.

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Achieving a correct description of materials with open and highly localized d and f shells (strongly correlated materials) by density functional theory (DFT) remains among the most challenging tasks in theoretical condensed matter physics [1]. Over the past about five decades DFT has been spectacularly successful in calculating material properties as well as designing novel materials with superior characteristics [2, 3]. For many elements and compounds, the exchange correlation functionals required for DFT calculations can be satisfactorily described using the local density approximation (LDA), or generalized gradient approximation (GGA) achieving very good agreement with experimental data [4, 5]. These standard approximations, however, fail to describe strongly correlated systems because of uncompensated self-interactions that introduce large errors. Consequently, the localized states in Mott insulators, or f electron systems cannot be properly treated within the LDA or GGA. To overcome these problems several methods have been proposed to improve the electron potentials by taking into account their dependence on orbital occupation. The most effective and accurate methods are: self-interaction corrected LDA [6], LDA+U [7], hybrid functional method [8], dynamical mean field theory (DMFT) [9], and reduced density matrix functional theory (RDMFT) [10]. The combination of DFT and DMFT [11] has recently been proven to be a particularly suitable approach for treating the strong electron-electron interactions in $3d$, $4f$ and $5f$ elements and compounds [12], exhibiting nevertheless some limitations [13]. In spite of its success and continuous development, the DFT+DMFT remains a computationally expensive and demanding method.

The frequencies of lattice vibrations are determined by the inter-atomic forces and constitute a sensitive data

set for verification of computational models. In strongly correlated systems, the DFT calculations often fail to correctly describe the phonon energies and experimentally observed phonon anomalies [14]. In many cases the improvement of density functionals results in a better description of the lattice dynamics in transition-metal oxides [15–19], actinide compounds [20], and rare earth oxides [21].

Currently there is an increasing need for a reliable predictive calculations of the lanthanides and their compounds as this class of materials is of great interest for both fundamental research and modern technology. The lanthanides are characterized by occupation of the $4f$ shell and exhibit strong electron correlations, complex magnetic order and in some cases large spin-orbit interactions that constitute a formidable challenge for theoreticians. In the *standard approach* the $4f$ electrons are treated as core states, and for the heavy rare earths (Gd-Lu) this approximation reproduces many physical properties [22–24]. When going from the heavy to the light lanthanides (Ce-Sm), however, the disagreement between theory and experiment gradually increases due to the more delocalized nature of the $4f$ electrons [24]. A continuous improvement in the calculation of electronic and structure properties of rare earth metals was achieved using the above mentioned approaches [25–28]. Despite these efforts, a systematic study of the influence of the $4f$ electron correlations on the lattice dynamics of the light lanthanides has not been performed so far.

The experimental investigation of pure lanthanides is also a demanding task because of difficulties to obtain single crystals of high quality and purity, high oxidation ability, and in some cases large absorption cross-sections for thermal neutrons. Due to these obstacles the lattice dynamics of some of the $4f$ elements has not yet been

determined despite decades of research. A successful experimental approach is to produce high quality single-crystalline films by molecular beam epitaxy and to perform the experiments *in situ* [29, 30] or, as demonstrated here, *ex situ* after covering the film by a protective layer.

In this paper we investigate the influence of the 4*f* electron correlations on the lattice dynamics of light lanthanide neodymium (Nd). The results from DFT calculations are compared to phonon dispersions measured by inelastic X-ray scattering (IXS) on a Nd(0001) film. We demonstrate that GGA+U, being the simplest approach for including local electron correlations, results in a very good agreement with experiment.

The DFT calculations were performed using the VASP code [31]. The electron wave functions and charge density were optimized by solving the Kohn-Sham equations within the projector-augmented wave method [32] and generalized gradient approximation [33]. The local interactions between the 4*f* valence electrons were included within the GGA+U method [7] with the Coulomb parameter $U = 4.8$ eV and Hund's exchange $J = 0.6$ eV taken from constrained random-phase approximation studies [34]. The results obtained with the GGA+U are compared to calculations with 4*f*-band (standard GGA) and with 4*f*-core (GGA₀) electron potentials. We assumed a ferromagnetic order with the optimized magnetic moments equal to $3.4 \mu_B$ and investigated the effect of spin-orbit coupling (SOC) on the lattice parameters and phonon energies. We used the controlled symmetry reduction method to eliminate metastable states in the GGA+U calculations [35].

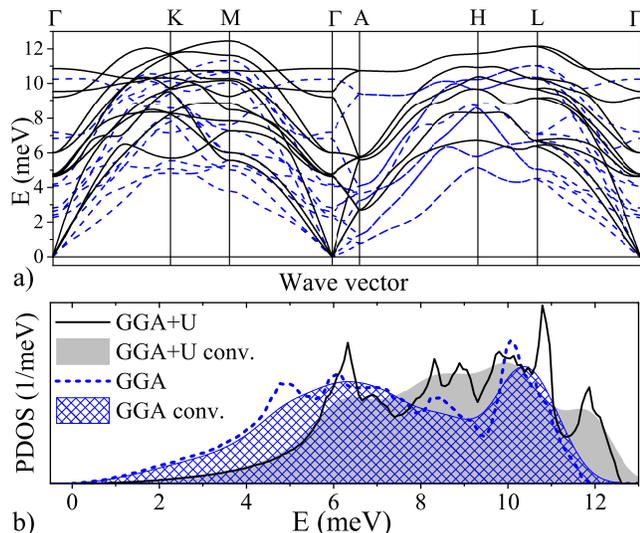


FIG. 1. *Ab initio* calculated a) dispersion relations and b) PDOS of Nd within GGA and GGA+U using the optimized lattice constants. The high symmetry points in units of $2\pi/a$ are $\Gamma = (0,0,0)$, $K = (\frac{1}{3}, \frac{1}{3}, 0)$, $M = (\frac{1}{2}, 0, 0)$, $A = (0, 0, \frac{1}{2})$, $H = (\frac{1}{3}, \frac{1}{3}, \frac{1}{2})$, $L = (\frac{1}{2}, 0, \frac{1}{2})$. Shaded areas correspond to the Gauss convolution with FWHM=1 meV.

Different approximations were tested using the *dhcp* primitive cell (space group $P6/mmc$) with four Nd atoms. The reciprocal space was sampled with a $8 \times 8 \times 8$ k-point Monkhorst-Pack grid [36] and an energy cutoff of 320 eV, which resulted in well converged values of the total energy and lattice parameters. The bulk modulus, its derivative and the elastic constants were determined at the theoretical equilibrium volumes using the stress-strain approach [37].

The phonon calculations were performed within the direct method implemented in the Phonon software [38] used previously for lattice dynamics studies of Eu [29] and Sm [30]. The Hellmann-Feynmann forces and force constants were obtained by displacing atoms from the equilibrium positions in the 32-atom supercell. The k-point sampling was reduced to a $4 \times 4 \times 4$ grid. The number and directions of necessary displacements were determined by the hexagonal symmetry constraints. The phonon dispersions and polarization vectors were obtained by diagonalization of the dynamical matrix. The dispersion relations along high symmetry directions and phonon density of states (PDOS) obtained with the optimized lattice parameters [39] are presented in fig. 1.

An epi-polished, A-plane $\text{Al}_2\text{O}_3(11\bar{2}0)$ substrate was subjected to a solvent degrease process followed by annealing at 1273 K for 1 h in a UHV chamber with a base pressure of 3×10^{-11} mbar. A 30 nm thick Nb(110) buffer layer was deposited at 1223 K on the substrate. Metallic Nd (supplied by the Ames Laboratory) with a purity of 99.99% was deposited on the Nb(110) layer, adapting the conditions established by Dufour *et al.* [40]. The substrate temperature was elevated during deposition to 873 K to enhance surface mobility, necessary for the formation of the Nd(0001) film with a thickness of about $1 \mu\text{m}$ (fig. 2 a)). The LEED image in fig. 2 b) reveals the formation of an atomically flat Nd(0001) surface with a hexagonal symmetry. Fig. 2 c) plots the X-ray diffraction scan measured after covering the sample with a 20 nm thick Nb layer to avoid oxidation. The data analysis confirmed the formation of a high quality and

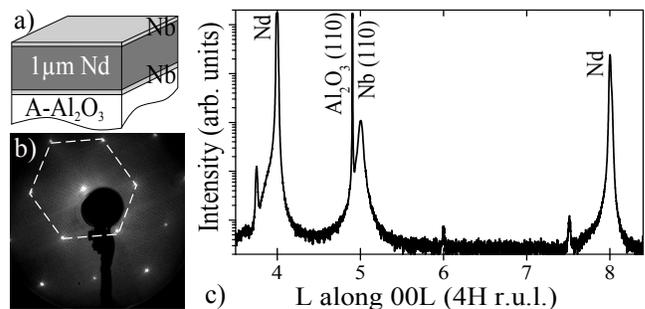


FIG. 2. a) Schematic presentation of the investigated sample. b) LEED image (obtained at 100 eV) of the Nd(0001) surface. The hexagonal *ab*-plane is indicated by broken white lines. c) XRD scan along 00L in *dhcp* 4H reciprocal lattice units.

TABLE I. Lattice constants (a , c), volume per one atom (V), and thermoelastic properties (bulk modulus B , derivative of the bulk modulus B' , elastic constants c_{xy} , and lattice specific heat C_V at 300 K) of Nd.

Property	GGA ₀	GGA	GGA+U(SOC)	Exp.
a (Å)	3.690	3.528	3.669 (3.670)	3.658*
c (Å)	11.870	11.277	11.804 (11.824)	11.797*
V (Å ³ /atom)	34.997	30.389	34.398 (34.470)	34.18*
B (GPa)	34.7	18.6	31.4 (32.15)	31.8*
B' (GPa)	3.09	2.41	3.05 (3.04)	2.9†
c_{11} (GPa)	59.9	31.4	55.2	58.78‡
c_{33} (GPa)	72.2	39.1	65.1	65.13‡
c_{12} (GPa)	29.8	14.9	27.9	24.58‡
c_{13} (GPa)	16.5	11.1	14.2	16.20‡
c_{44} (GPa)	18.8	6.3	18.5	16.20‡
C_V (J/mol K)	24.67	24.75	24.69	24.68*

*[41], †[42], ‡[43], *[44]

purity single-crystalline Nd(0001) film with a negligible amount of polycrystalline phases. The c -lattice constant (11.796 Å) of the Nd sample determined from the XRD measurement is in very good agreement with the published data (Table I).

The IXS experiment [45] was performed at the beamline ID28 of the European Synchrotron (ESRF) with an energy resolution of 3.0 meV (full width at half maximum) at a photon energy of 17.794 keV. During the measurement the sample was kept at room temperature in a vacuum of 5×10^{-6} mbar. The experiment was performed in grazing incidence geometry at an incidence angle of 0.4° . Due to this experimental constraint the phonon branches with both transverse and longitudinal polarizations were measured close to the directions $\Gamma \rightarrow K \rightarrow M$ and $\Gamma \rightarrow M \rightarrow \Gamma$ with an offset in z -direction. Along $\Gamma \rightarrow A$, the branches with longitudinal polarization were measured without an offset. A list of the measured branches is given in Table II. The phonon energies were obtained by fitting a model function composed of a sum of Lorentzian profiles to the experimental data.

TABLE II. Direction, polarization (longitudinal acoustic/optic (LA/LO), transverse acoustic/optic (TA/TO)), and exact coordinates of the measured phonon branches in reciprocal lattice units.

Direction	Mode	Momentum transfer
$\Gamma \rightarrow K \rightarrow M$	LA/LO	$[1+q \ 1+q \ 0.2]$ ($0.1 \leq q \leq 0.5$)
	TA/TO	$[3-q \ -3-q \ 0.3]$ ($0.1 \leq q \leq 0.5$)
$\Gamma \rightarrow A$	LA/LO	$[0 \ 0 \ 2+q]$ ($0 \leq q \leq 1.6$)
$\Gamma \rightarrow M \rightarrow \Gamma$	LA/LO	$[2+q \ -2-q \ 0.2]$ ($0.1 \leq q \leq 0.9$)
	TA/TO	$[1-q \ 1+q \ 0.2]$ ($0.6 \leq q \leq 1.8$)

A comparison of the calculated and experimentally determined lattice constants (Table I) reveals a strong effect of the local Coulomb interaction U and a rather minor influence of the SOC. While GGA underestimates the experimental lattice constants by about 4%, GGA+U results in an agreement of better than 0.1%. This shows that the interaction terms with U and J introduce relevant corrections to the atomic bonding. The bulk modulus and elastic constants obtained within GGA+U are in very good agreement with the available experimental data (Table I). The effect of SOC on the bulk modulus and its derivative is very weak. As already shown in previous studies [24, 28], the structural and elastic parameters obtained within the $4f$ -core model GGA₀ are overestimated exhibiting, however, better agreement with experiment than the $4f$ -band GGA calculations, which significantly underestimate the bulk modulus [28].

A comparison of the dispersion relations calculated with GGA and GGA+U (fig. 1 a)) reveals a remarkable shift of the phonon branches to higher energies for GGA+U. A splitting of the high energy modes results in an effective broadening of the PDOS that is clearly visible in fig. 1 b) [46]. The increase of inter-atomic forces originates from the implemented local Coulomb and exchange interactions. Apparently, the origin of this result is the modification of electronic properties, namely an enhanced localization of the $4f$ electrons, consequently a reduced screening obtained by the GGA+U. This results in augmented inter-atomic forces compared to the GGA values, despite the larger lattice constants obtained by the latter.

The experimental phonon dispersions were obtained with an offset in z -direction due to the employed grazing incidence scattering geometry, and they cannot be directly compared with the calculations presented in fig. 1 a). Therefore, GGA+U calculations were performed for the exact experimental directions (Table II) and compared with the experimental points in fig. 3. In order to identify the most intense phonon branches, the dynamical form factor was calculated [39] and presented in color scale. Close to the directions $\Gamma \rightarrow K \rightarrow M$ and $\Gamma \rightarrow M \rightarrow \Gamma$ for both longitudinal, fig. 3 a), d), and transverse, fig. 3 b), e) polarizations, the experimental points coincide with the calculated branches of highest intensities with an average deviation of 6.5%. Attribution of the experimental points to close-lying branches is limited by the experimental energy resolution. This is for example visible in fig. 3 e) where at $q = 1.7$ the experimental point appears between two close-lying branches of similar intensity and separated by less than 2 meV. Along the $\Gamma \rightarrow A$ direction (fig. 3 c)) a deviation of 8.1% from the theory is found at small q , while the agreement improves to 2% at higher q values.

The remarkable agreement between the experimental and theoretical phonon dispersions is a direct proof that GGA+U introduces important corrections to the inter-

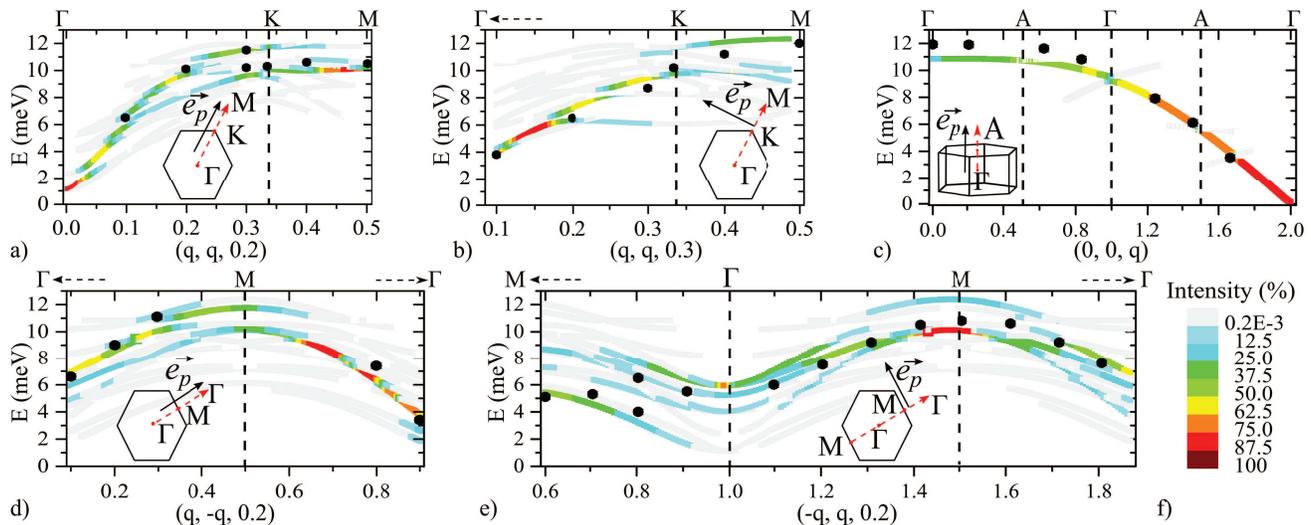


FIG. 3. Comparison between the GGA+U calculated (colored lines) and measured by IXS (black circles, error bars are comparable to the symbol size) phonon branches close to a), b) $\Gamma \rightarrow K \rightarrow M$, c) along $\Gamma \rightarrow A$ and d), e) close to $\Gamma \rightarrow M \rightarrow \Gamma$ directions. The intensity scale is shown in f). The directions, polarizations and exact coordinates of the measured branches are listed in Table II. The phonon polarization vector \vec{e}_p (black arrows), direction of the momentum transfer (red dashed arrows) and *dhcp* Brillouin zone (black hexagon/structure) are shown as insets. Details about the calculation of the intensity of the phonon branches is given in [39].

atomic forces. Calculations with GGA, without including electron correlations, result in a down shift of the dispersion relations on the energy scale by about 2 meV and a change in the slopes of the acoustic branches, leading to unacceptably large deviations from the experimental data. As a consequence a disagreement by more than 30% between the experimental and theoretical elastic constants obtained in GGA is evidenced by Table I. Within the *4f*-core model, the acoustic branches are well described but the high-energy optical modes are strongly overestimated [39].

The larger bulk modulus obtained with the GGA+U seems to contradict the typical observation that elastic parameters are reduced by the electron localization. However, in light rare earths, the localized *4f*-core model gives larger values of the bulk modulus (and volume) [24] compared to the *4f*-band model [28]. Therefore, the local Coulomb interaction (U), which induces partial localization of the *4f* electrons, also increases the bulk modulus and gives much better agreement with the experiment than the *4f*-band calculations.

The effect of electron correlations on the lattice dynamical properties, discussed here for Nd, may be as well a general feature of the other lanthanides. For example, the experimentally observed broadening of optical modes in the PDOS of Sm, which leads to some discrepancy between experiment and theory [30], most likely has its origin in a splitting of the high energy modes found in the Nd PDOS. This is demonstrated by a comparison of the PDOS convoluted with a Gaussian with FWHM=1 meV for calculations with GGA and GGA+U

in fig. 1 b). At this energy resolution the splitting of the high energy phonon branches results in an overall broadening mostly of the optical modes of the PDOS calculated with GGA+U.

In summary, we have performed a combined theoretical (DFT) and experimental (IXS) study of the lattice dynamics of the light rare earth element Nd. The calculations within GGA₀, GGA and GGA+U revealed a drastic influence of the *4f* electron correlations on the lattice dynamics of Nd. The dispersion curves obtained within GGA+U were confirmed to be correct by achieving an overall agreement of better than 7% with the IXS experimental data. The Coulomb interaction U leads to a partial electron localization reducing the screening effects of the *4f* electrons and consequently to a very good agreement of the calculated lattice constants and elastic properties with the experimental values. This provides a better description of the properties of Nd than the fully localized *4f*-core model.

The presented results clearly demonstrate that: (i) *4f* electron correlations have a remarkable influence on the lattice dynamics of the rare earth metals. The calculated inter-atomic forces and phonon energies appear to be strongly reduced and therefore erroneous if these interactions are not taken into account; (ii) GGA+U provides a reliable description of the electronic properties and lattice dynamics of the light lanthanides.

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phonon dispersions and PDOS of the strongly correlated $3d$ oxides NiO and MnO were reported in Ref. 18.